

Technical Data of Crystal Unit								
MURATA Part No.:	MURATA Part No.: XRCMD32M000FXP53R0							
Applied to	JN5169							
Murata Manufacturing Co., Ltd.								



■ Murata's recommendation 推奨回路定数

Item		Condition				
IC name		IC名		JN5169		
Parts Number of Crystal Unit		品番		XRCMD32M000FXP53R0		
Circuit Parameter	External	負荷容量	CL1	10pF		
	load capacitance	負荷容量	CL2	10pF		
	Feedback resistance	帰還抵抗	Rf	No mount		
	Damping resistance	制限抵抗	Rd	0ohm		
Supply Voltage		電源電圧		5V		
Temp. Range		温度範囲	•	-40 to 85deg.C		

Test Circuit Set : 5V Evaluation board JN5169 Rf Rd≤ Crystal Unit VIN VOUT CL2 +

Xin:5 Xout:4

Crystal Unit: XRCMD32M000FXP53R0

Set =5V
CL1 =10pF
CL2 =10pF
Rf: No mount Rd =0ohm Ta =-40 to 85deg.C

Measurement equipment Oscilloscope

Current probe CT-6(T) P5100A(T) (40Mohm/2.5pF) Passive probe Frequency counter 53181A(K) Sepectrum analyzer E4401B(K)

(K) Keysight (T) Tektronix

■ Characteristics of oscillation circuit on above condition 推奨定数での発振回路特性

Circuit Characteristics 特性	Value 測定値			Remarks 備考		
Center Frequency and Difference 発振回路における発振周波数とそのずれ量 (*1)		31.999984		Oscillating frequency and its shift against nominal frequency 発振回路における発振周波数と振動子の公称周波数に対す		
(Typical sample at Set=5V,+25deg.C)	-(-0.5		ずれ量		
Load Capacitance on your PCB 負荷容量値 (Typical sample at Set=5V,+25deg.C)	6.1 [pF]		[pF]	This value shows load capacitance the evaluated circuit h 発振回路において振動子の両端に仮想的に接続される容		
Negative Resistance and Oscillation margin 負性抵抗/発振余裕度	-R	856	[Ω]	The details is explained in page 2 詳細につきましては、次頁をご参照下さい。		
(at Set=5V,+25deg.C)	Ratio	10.7	[Times]			
Drive Level ドライブレベル (Typical sample at Set=5V,+25deg,C)	62	62.8		Drive power of crystal under circuit condition 発振回路が動作している状態において振動子で消費される 電力		
Oscillating Voltage 発振電圧	VINp-p	1.3	[V]	Swing level at input side 発振入力振幅 (VIN_H - VIN_L)		
(Typical sample at Set=5V,+25deg.C)	VOUTp-p	1.1	[V]	Swing level at output side 発振出力振幅 (VOUT_H - VOUT_L)		
Oscillation Start up Time 起動時間 (*2) (Typical sample at Set=5V,+25deg,C)	2.	2.44 [ms]		Time to reach 90% of the oscillation level under steady state 定常状態の発振振幅の90%に達するまでの時間		

^{*1} Frequency difference means the oscillating frequency difference between your PCB and Murata's frequency sorting circuit. 責社基板と当社検査回路では、同一振動子を使用した場合でも発振周波数の差が生じます。これを発振周波数相関と呼びます。
*2 The measurement results is affected by the rise-up characteristics of supplied voltage on your PCB. 測定結果は実装基板の電源立ち上がり特性の影響を受けます。

The characteristics of the crystal oscillation circuit is affected by the circuit constants and actual mounting conditions and so on. Therefore, it is possible to get the different results from above one due to the production variation of the crystal oscillator circuitry.

In your company, please use this results after confirmation of the matching between our crystal unit and oscillator circuit.

And furthermore, since the above-mentioned evaluation results evaluate only an oscillating circuit block, please confirm the checking of operations of a set in your company.

注意事項

体のデタス 発振回路の特性は回路定数や実装状態により影響を受けるため、回路や基板のパラツキ等によっては上記の結果と異なる可能性があります。 貴社におかれましても弊社水晶振動子と発振回路とのマッチングをご確認の上、ご使用下さるようお願い致します。 また上記評価結果は発振回路ブロックのみを評価したものですので、セットの動作確認は貴社にてご確認下さるようお願い致します。

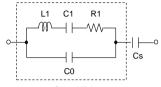
Murata Manufacturing Co., Ltd.



■ Test Data : Characteristics of recommended conditions

The following values are for the arbitrary sample and only for your reference.

Electrical equivalent circuit of crystal unit and Cs



Fr: Resonant frequency

R1 Equivalent series resistance ESR

C1 Series capacitance C0 Series capacitance

L1 Series inductance

Cs Load capacitance FL Load resonant frequency

Crystal Unit

Electrical circuit constants of a crystal unit

Cs=6pF

No.	FL		S	Fr	R1	C1	Q(10^4)	C0	r	L1
	[MHz]	[ppm]	[ppm/pF]	[MHz]	[Ω]	[fF]		[pF]		[mH]
1	32.000011	0.3	12.6	31.997769	31.4	1.05	15.1	0.46	438	23.6

Center frequency

31.999984 MHz

Center frequency difference

-0.5 ppm from 32MHz

This frequency difference causes imbalance of initial frequency tolerance on your PCB, because of load capacitance difference.

Load capacitance of the circuit

This value shows load capacitance the evaluated circuit has

Our crystal proposed in this report is sorted with 6pF as load capacitance

Negative resistance

Ratio of negative resistance |-R| to R1spec.

10.7 times Ratio

Re: 36.4 ohm

Effective resistance of Crystal Unit at actual oscillation frequency

Effective resistance Re=R1x(1+C0/CL)²

80 ohm R1spec. Equivalent series resistance

Drive level

Drive power of crystal under circuit condition shown in page 1

Drive level 62.8 uW

Drive level =
$$I^2 \times R1$$

31.4 ohm

Murata Manufacturing Co., Ltd.



